

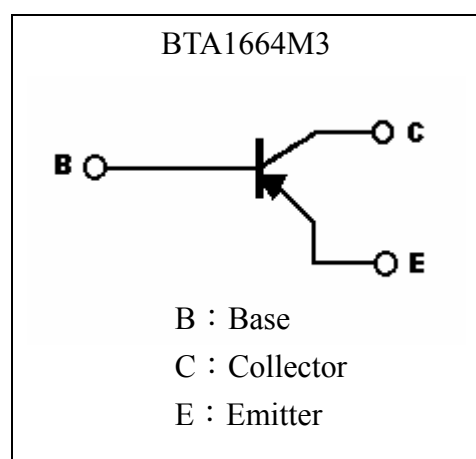
Low Vcesat PNP Epitaxial Planar Transistor

BTA1664M3

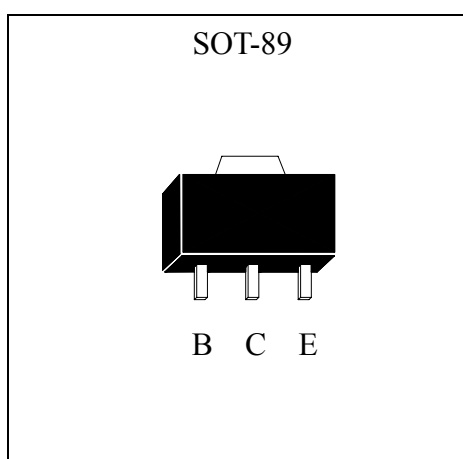
Features

- Low $V_{CE(sat)}$, $V_{CE(sat)} = -0.24V$ (typical), at $I_C / I_B = -500mA / -20mA$
- Pb-free lead plating and halogen-free package

Symbol

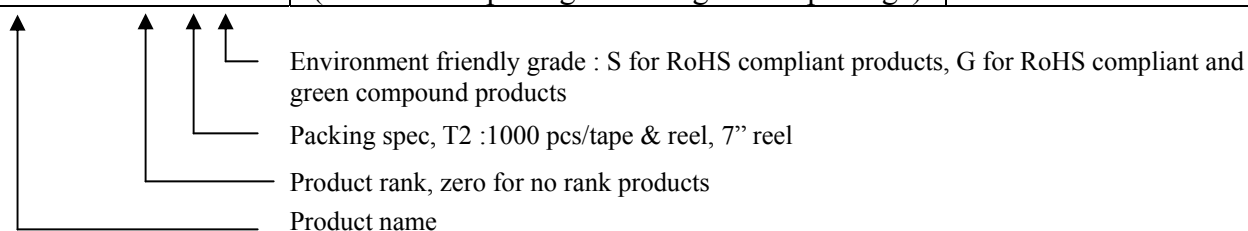


Outline



Ordering Information

Device	Package	Shipping
BTA1664M3-X-T2-G	SOT-89 (Pb-free lead plating and halogen-free package)	1000 pcs / Tape & Reel



**Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-35	V
Emitter-Base Voltage	V _{EBO}	-7	V
Collector Current(DC)	I _C	-2	A
Peak Collector Current	I _{CM}	-4 *1	A
Peak Base Current	I _{BM}	-200	mA
Power Dissipation	P _D	0.6	W
		1.5 *2	
		2.1 *3	
Thermal Resistance, Junction to Ambient	R _{θJA}	208	°C/W
		83.3 *2	
		59.5 *3	
Thermal Resistance, Junction to Case	R _{θJC}	39	
Operating Junction and Storage Temperature Range	T _j ;T _{stg}	-55~+150	°C

Note :1 Single pulse, Pw=10ms

2 When mounted on 25mm×25mm×1.6 mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air condition

3 When mounted on 50mm×50mm×1.6 mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air condition

Characteristics (Ta=25°C)

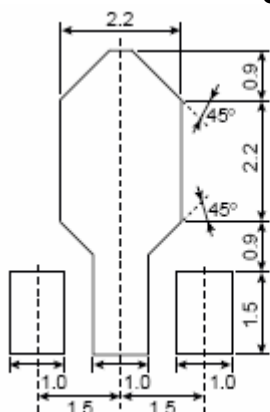
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CBO}	-50	-	-	V	I _C =-50μA, I _E =0
BV _{CEO}	-35	-	-	V	I _C =-1mA, I _B =0
BV _{EBO}	-7	-	-	V	I _E =-50μA, I _C =0
I _{CBO}	-	-	-100	nA	V _{CB} =-50V, I _E =0
I _{EBO}	-	-	-100	nA	V _{EB} =-7V, I _C =0
*V _{CE(sat)}	-	-0.24	-0.4	V	I _C =-500mA, I _B =-20mA
*V _{CE(sat)}	-	-	-0.5	V	I _C =-800mA, I _B =-80mA
*V _{BE(on)}	-0.5	-	-0.8	V	V _{CE} =-1V, I _C =-10mA
*h _{FE} 1	120	-	390	-	V _{CE} =-1V, I _C =-100mA
*h _{FE} 2	40	-	-	-	V _{CE} =-1V, I _C =-800mA
f _T	-	120	-	MHz	V _{CE} =-5V, I _C =-10mA, f=100MHz
Cob	-	19	-	pF	V _{CB} =-10V, f=1MHz

*Pulse Test : Pulse Width ≤380μs, Duty Cycle≤2%

Classification of h_{FE} 1

Rank	Q	R
Range	120~270	180~390

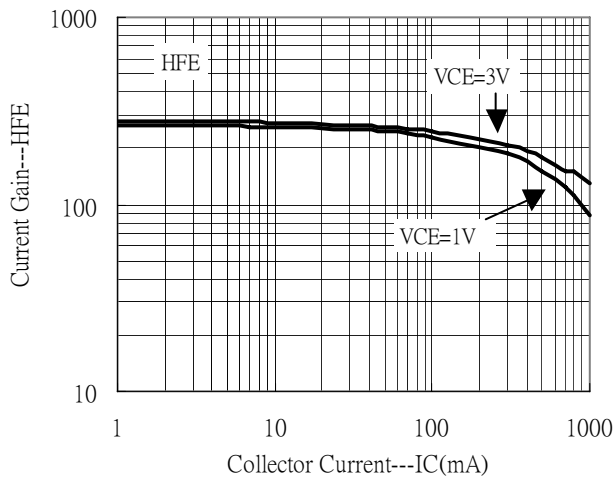
Recommended soldering footprint



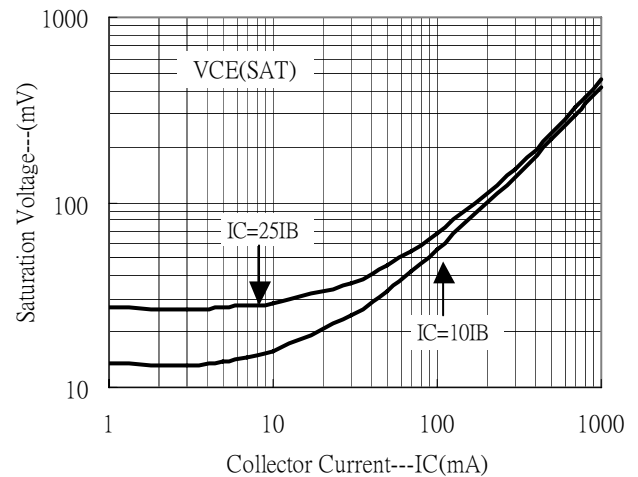
unit : mm

Characteristic Curves

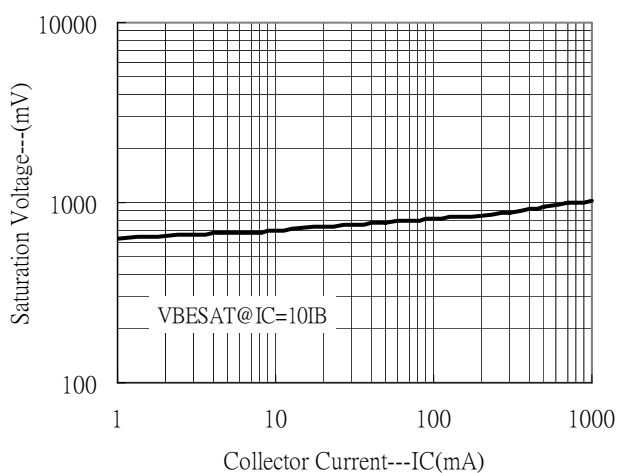
Current Gain vs Collector Current



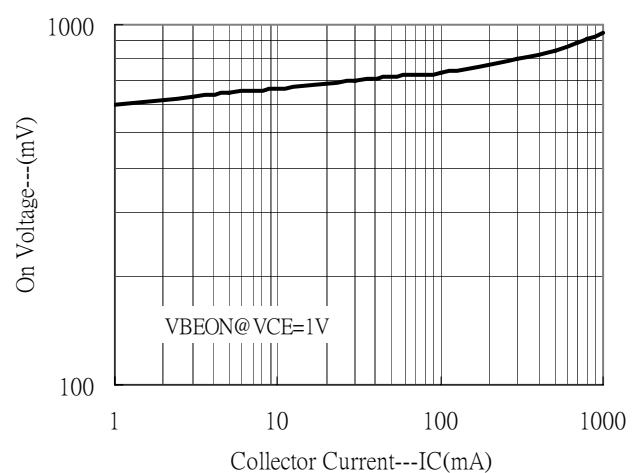
Saturation Voltage vs Collector Current



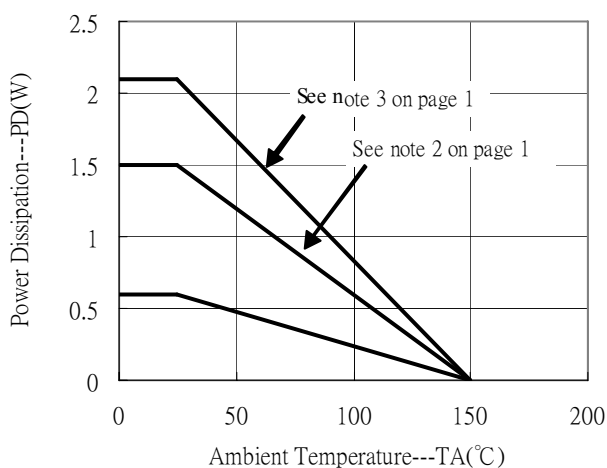
Saturation Voltage vs Collector Current



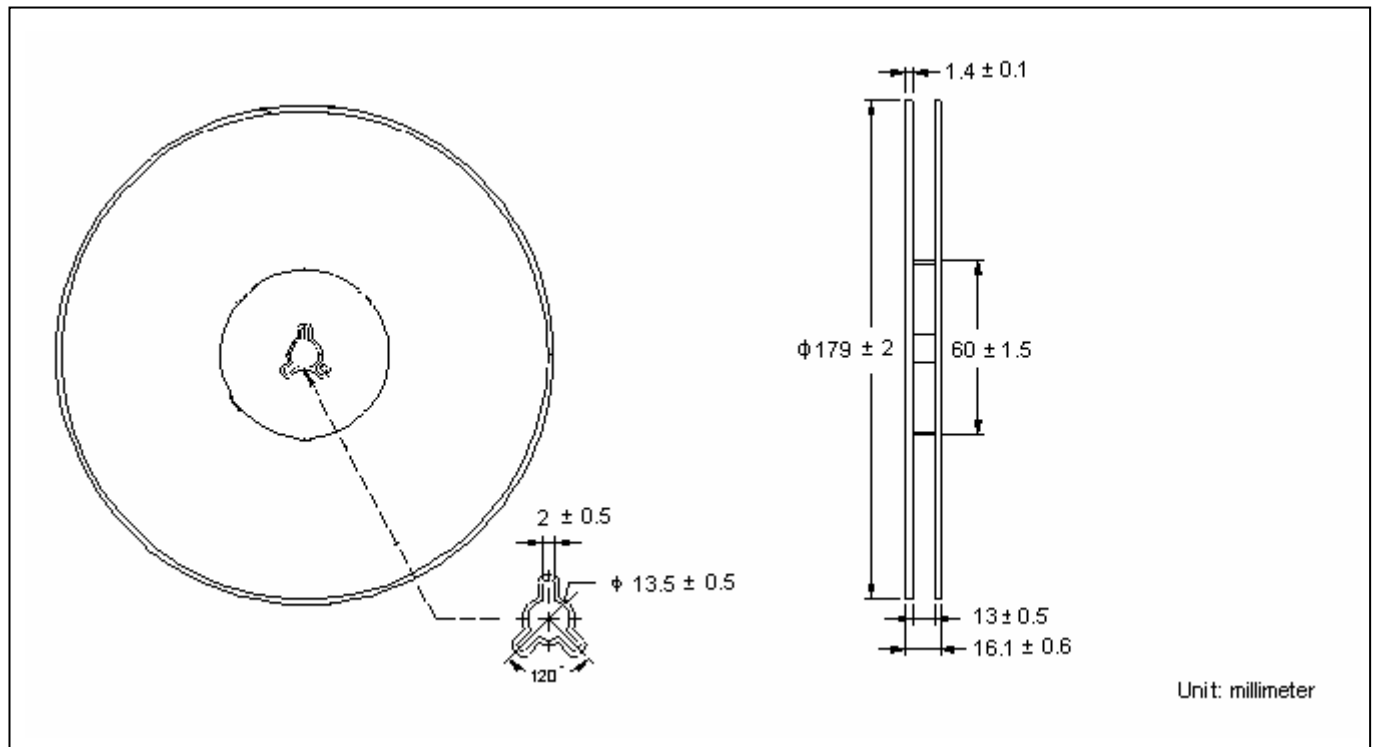
On Voltage vs Collector Current



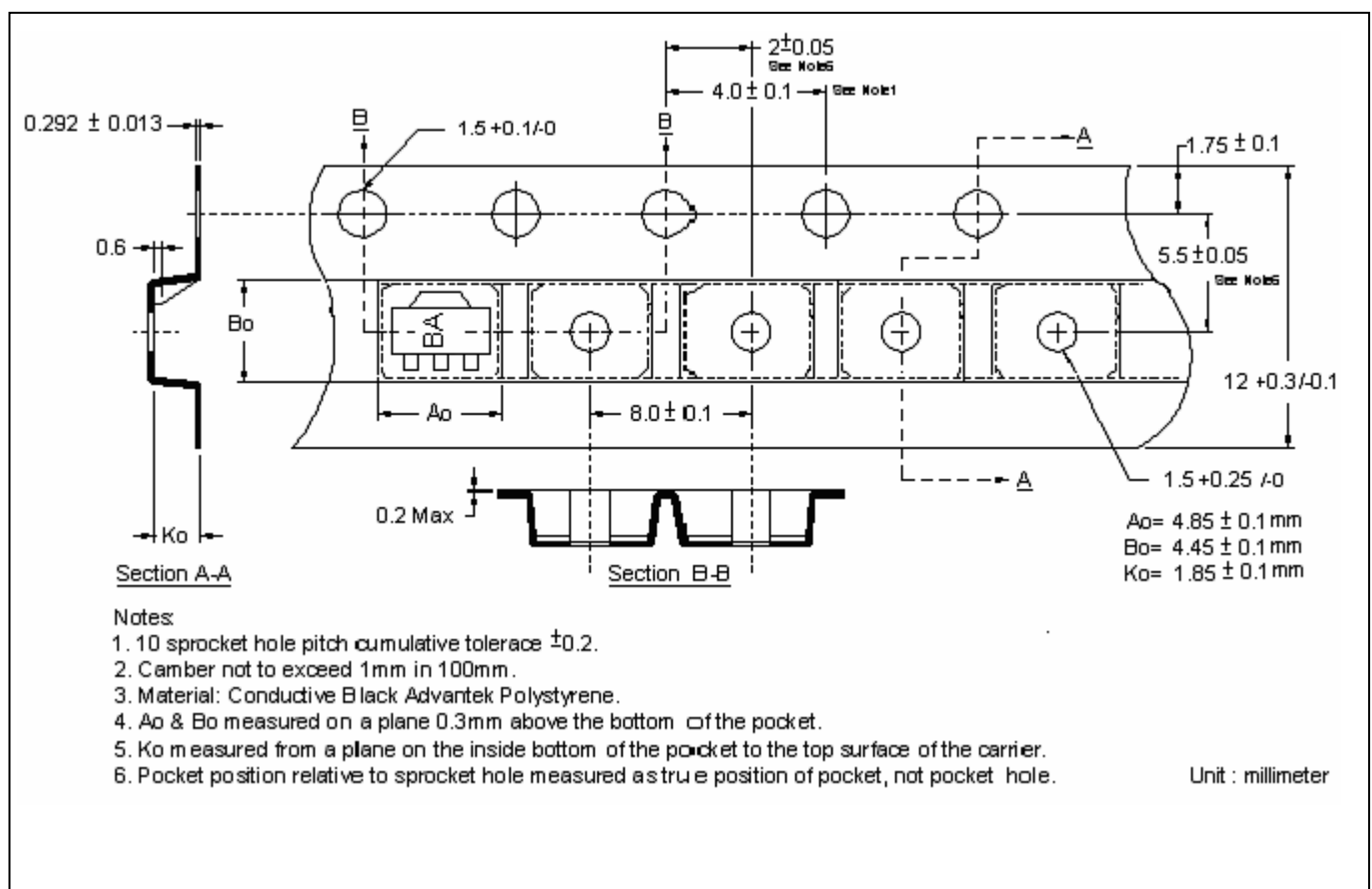
Power Derating Curves



Reel Dimension



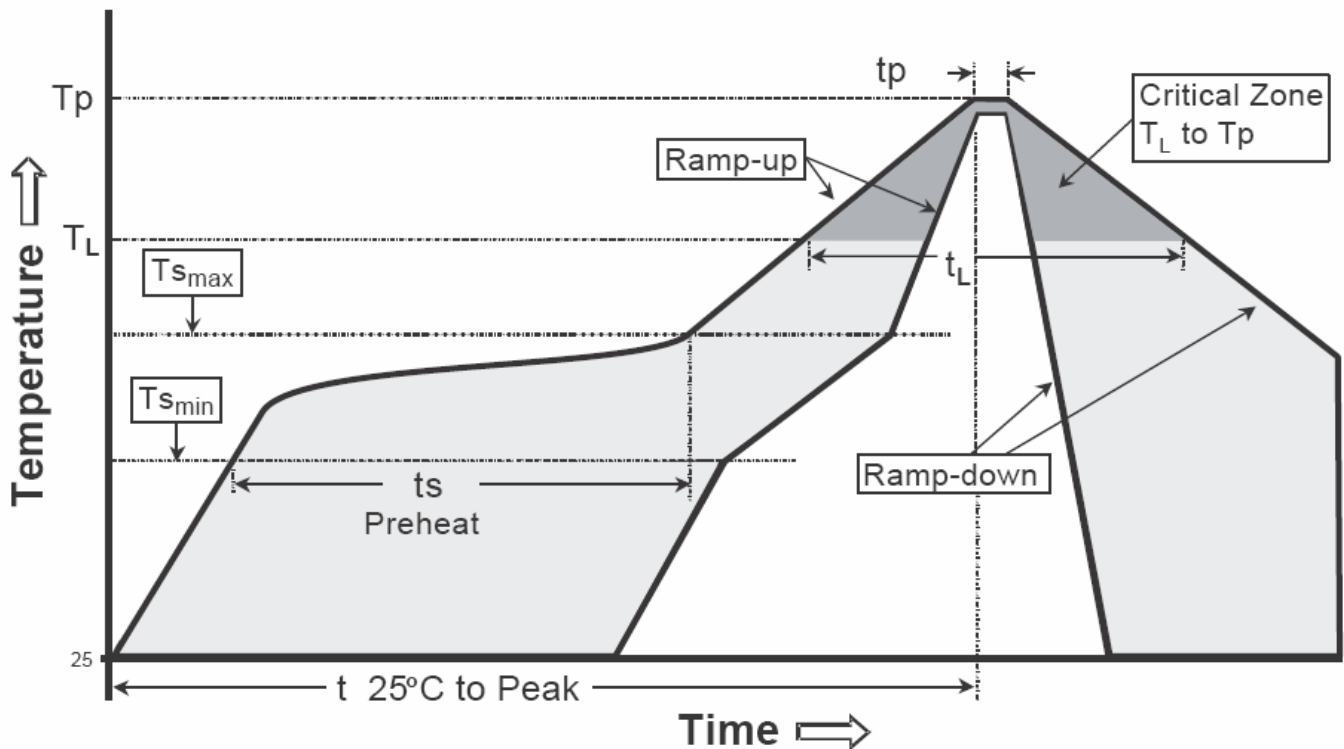
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

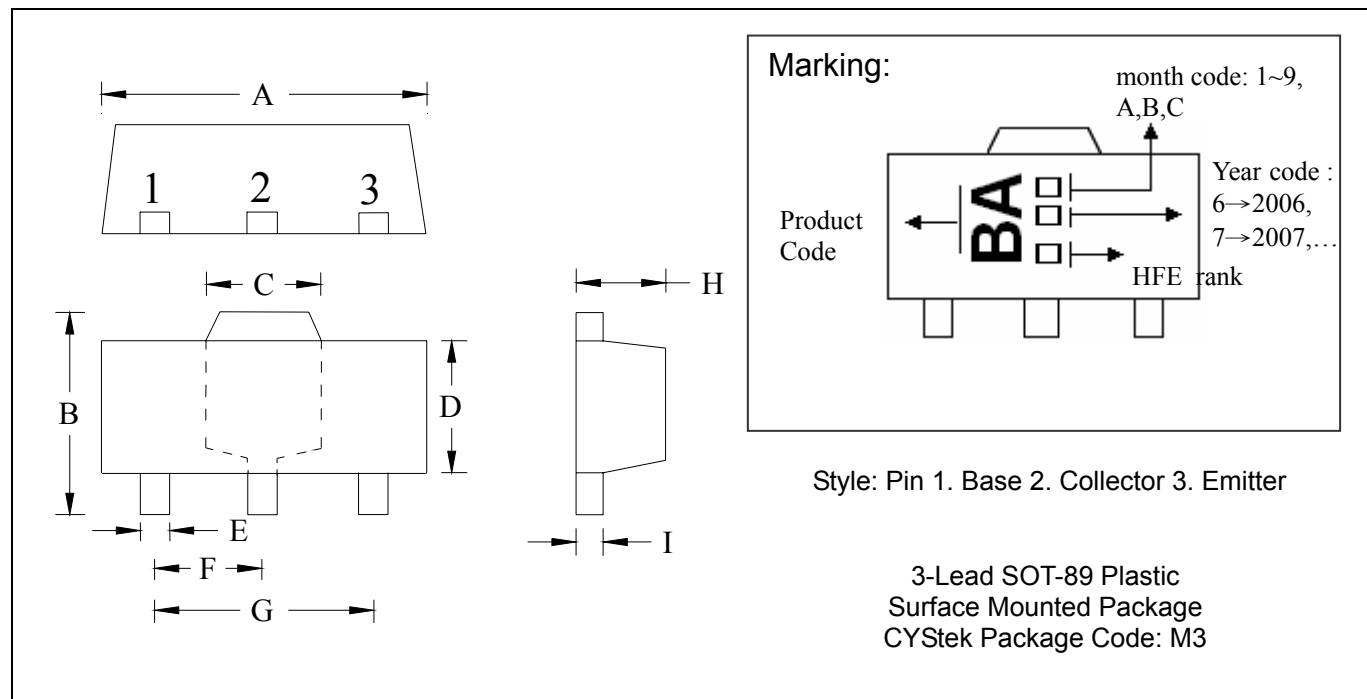
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T_{smax} to T_p)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(T_{smin})	100°C	150°C
-Temperature Max(T_{smax})	150°C	200°C
-Time(t_{smin} to t_{smax})	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T_L)	183°C	217°C
- Time (t_L)	60-150 seconds	60-150 seconds
Peak Temperature(T_p)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(t_p)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOT-89 Dimension



DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1732	0.1811	4.40	4.60	F	0.0591	TYP	1.50	TYP
B	0.1551	0.1673	3.94	4.25	G	0.1181	TYP	3.00	TYP
C	0.0610	REF	1.55	REF	H	0.0551	0.0630	1.40	1.60
D	0.0906	0.1024	2.30	2.60	I	0.0138	0.0173	0.35	0.44
E	0.0126	0.0205	0.32	0.52					

Notes: 1.Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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